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138A, 80V N-CHANNEL MOSFET

DESCRIPTION

SVG083R6NAL5 is N-channel enhancement mode power MOS field effect transistor which is produced using Silan's LVMOS technology. The improved process and cell structure have been especially tailored to minimize on-state resistance, provide superior switching performance and high avalanche breakdown tolerance.

This device is widely used in power management for UPS and Inverter Systems.

FEATURES

- 138A, 80V, $R_{DS(on)(typ.)}$ =3.0m $\Omega@V_{GS}$ =10V
- Low gate charge
- Low Crss
- Fast switching
- Extreme dv/dt rated
- 100% avalanche tested
- Pb-free lead plating
- RoHS compliant

8 D S 2 6 5 D PDFN-8-5X6X0.95-1.27

KEY PERFORMANCE PARAMETERS

Characteristics	Ratings	Unit
V _{DS}	80	V
V _{GS(th)}	2.0~4.0	V
R _{DS(on),max}	3.6	mΩ
I _D	138	A
Q _{g.typ}	65	nC

ORDERING INFORMATION

Part No.	Part No. Package		Hazardous Substance Control	Packing Type	
SVG083R6NAL5TR	PDFN-8-5X6X0.95-1.27	PDFN-8-5X6X0.95-1.27 083R6NA		Tape & Reel	

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ABSOLUTE MAXIMUM RATINGS (UNLESS OTHERWISE NOTED, TJ=25°C)

Characteristics	Cumbal	ol Test conditions	Ratings			Unit	
Characteristics	Symbol	rest conditions	Min. Ty		Max.	Oilit	
Drain-source Voltage	V_{DS}		80			V	
Gate-source Voltage	V_{GS}		-20		20	V	
Drain Current (Note 1)		T _C =25°C			138	Α	
Drain Current (Note 1)	l _D	T _C =100°C			88	Α	
Drain Current Pulsed (Note 2)	I _{DM}	T _C =25°C			552	Α	
Power Dissipation (Note 3)	P_D	T _C =25°C			125	W	
Single Pulsed Avalanche Energy	E _{AS}	L=0.1mH, V_{DD} =50V, R_{G} =25 Ω , starting temperature T_{J} =25 $^{\circ}$ C			231	mJ	
Single Pulsed Avalanche Current	I _{AS}				68	Α	
Operation Junction Temperature Range	Τ _J		-55	1	150	°C	
Storage Temperature Range	T _{stg}		-55		150	°C	

THERMAL CHARACTERISTICS

Characteristics	racteristics Symbol Test condi	Test conditions		Ratings		Unit
Onaracteristics	Syllibol	rest conditions	Min.	Тур.	Max.	
Thermal Resistance,	$R_{\theta JC}$				1.0	°C/W
Junction-case, Bottom	ΝθJC					
Thermal Resistance,	D	D			50	°C/W
Junction-ambient	$R_{\theta JA}$				50	-0///
Soldering Temperature(SMD)	T_{sold}	Reflow soldering: 10±1 sec, 3times			260	°C

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ELECTRICAL CHARACTERISTICS (UNLESS OTHERWISE NOTED, TJ=25°C)

Static characteristics

Characteristics	Symbol	Test conditions	Ratings			Unit
Characteristics		rest conditions	Min.	Тур.	Max.	Offic
Drain-source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250μA	80			V
Drain-source Leakage Current		V _{DS} =80V, V _{GS} =0V, T _J =25°C			1.0	μΑ
	I _{DSS}	V _{DS} =80V, V _{GS} =0V, T _J =125°C		5.0		
Gate-source Leakage Current	I _{GSS}	V _{GS} =±20V, V _{DS} =0V			±100	nA
Gate Threshold Voltage	V _{GS(th)}	$V_{GS}=V_{DS}, I_{D}=250\mu A$	2.0		4.0	V
Static Drain-source	D	V _{GS} =10V, I _D =20A		3.0	3.6	mQ.
On State Resistance	$R_{DS(on)}$	VGS=1UV, ID=2UA		3.0	3.0	1117.7
Gate Resistance	R_g	f=1MHz		2.7		Ω

Dynamic characteristics

Characteristics	Council of	Took conditions	Rati		atings	
Characteristics	Symbol	Symbol Test conditions	Min.	Тур.	Max.	Unit
Input Capacitance	C _{iss}			4457		
Output Capacitance	Coss	f=1MHz, V _{GS} =0V, V _{DS} =40V		735		pF
Reverse Transfer Capacitance	C _{rss}			26		
Turn-on Delay Time	t _{d(on)}	V 40V V 40V D 400		35		
Turn-on Rise Time	t _r	V_{DD} =40V, V_{GS} =10V, R_{G} =10 Ω ,		69		
Turn-off Delay Time	t _{d(off)}	I _D =20A		80		ns
Turn-off Fall Time	t _f	(Notes 4, 5)		48		
Total Gate Charge	Qg			65		
Gate-source Charge	Q_{gs}	V _{DD} =40V, V _{GS} =10V, I _D =20A		25		nC
Gate-drain Charge	Q_{gd}	(Notes 4, 5)		12		
Gate-plateau Voltage	V _{plateau}			5.4		V

Reverse diode characteristics

Characteristics	Symbol Test conditions	Ratings			Unit	
Characteristics	Syllibol	rest conditions	Min.	Тур.	Max.	Onit
Continuous Diode Forward Current	Is	Integral reverse P-N junction			138	^
Diode Pulse Current	I _{S,pulse}	diode in the MOSFET			552	Α
Source-Drain Diode Voltage Drop	V_{SD}	I _S =20A, _{GS} =0V			1.4	V
Reverse Recovery Time	T _{rr}	I _S =20A, V _{GS} =0V, V _R =40V		59		ns
Reverse Recovery Charge	Q _{rr}	dI _F /dt=100A/μs (Note 4)		90		nC

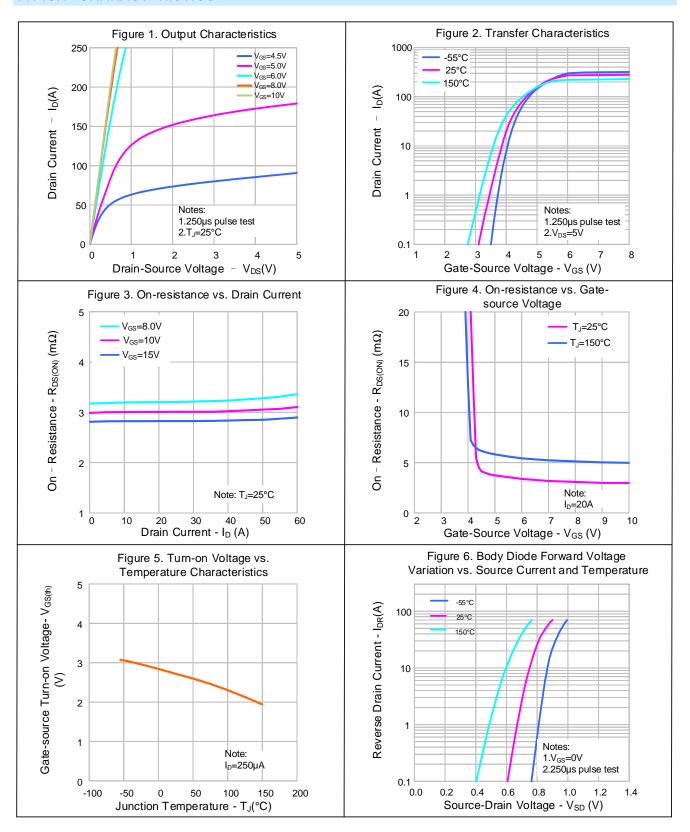
Notes:

- The rated value only refers to the maximum absolute value at the case temperature of 25°C in the specification. If the case 1. temperature is higher than 25°C, it should be derated according to the actual environmental conditions;
- 2.
- 3. The dissipation power will change with temperature, derating above 25°C: 1.0W/°C;
- 4. Pulse Test: Pulse width ≤300µs, Duty cycle≤2%;
- Essentially independent of operating temperature. 5.

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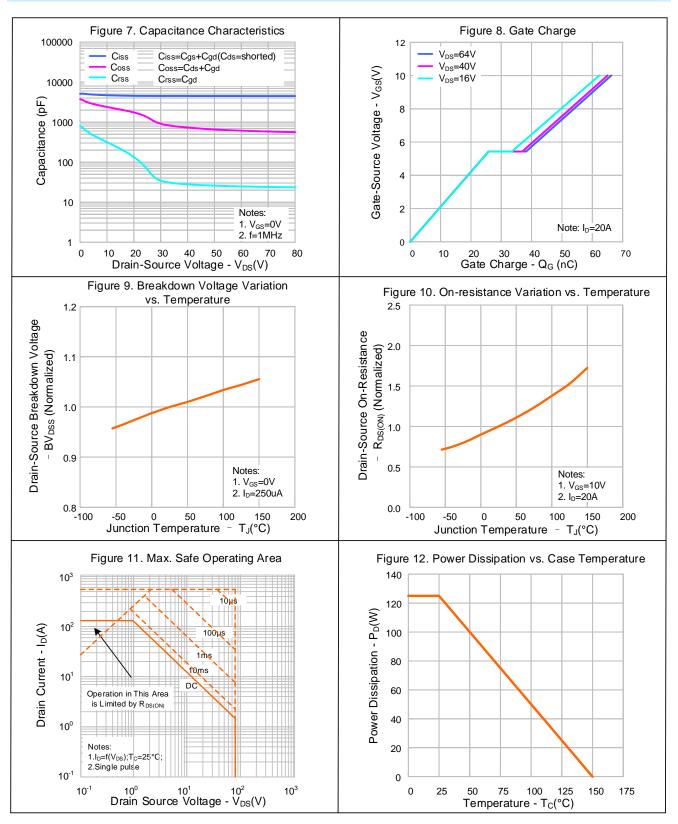
TYPICAL CHARACTERISTICS



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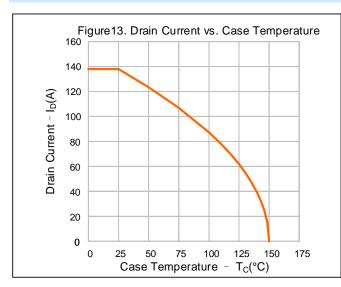
TYPICAL CHARACTERISTICS (CONTINUED)

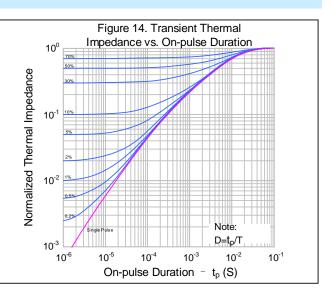


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TYPICAL CHARACTERISTICS (CONTINUED)



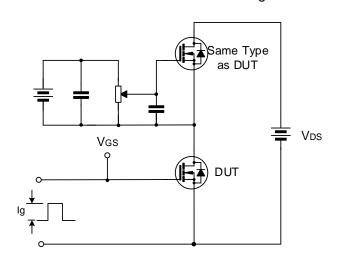


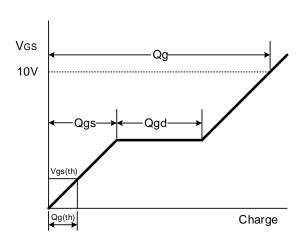
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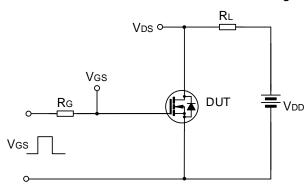
TYPICAL TEST CIRCUIT

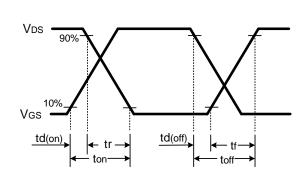
Gate Charge Test Circuit & Waveform



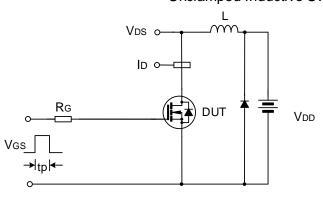


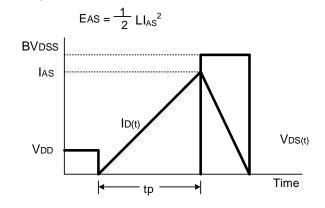
Resistive Switching Test Circuit & Waveform





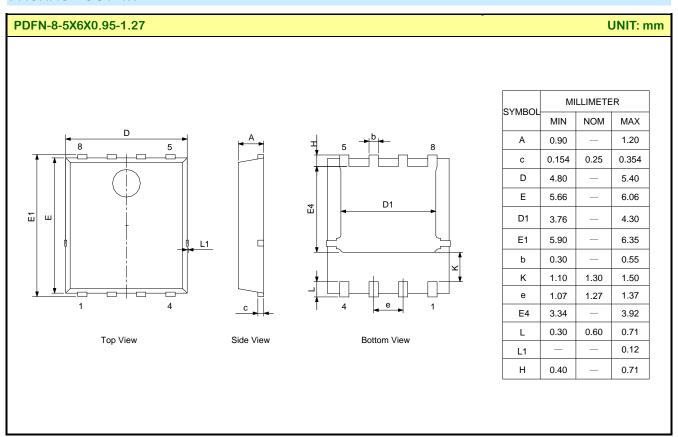
Unclamped Inductive Switching Test Circuit & Waveform







PACKAGE OUTLINE





MOS DEVICES OPERATE NOTES:

Electrostatic charges may exist in many things. Please take following preventive measures to prevent effectively the MOS electric circuit as a result of the damage which is caused by discharge:

- The operator must put on wrist strap which should be earthed to against electrostatic.
- Equipment cases should be earthed.
- All tools used during assembly, including soldering tools and solder baths, must be earthed.
- MOS devices should be packed in antistatic/conductive containers for transportation.

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Important notice:

- Silan reserves the right to make changes of this instruction without notice.
- 2. Customers should obtain the latest relevant information when purchasing and should verify whether such information is latest and complete. Please read this instruction and application manual and related materials carefully before using products, including the circuit operation precautions, etc.
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First release

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